L Number	Hits	Search Text	DB	Time stamp
76	60	(((laser NEAR diode) with (ridge or stripe)) and clad$4 and active and contact and electrode and voltage) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:04
87	111	((laser NEAR diode) with (ridge or stripe)) and (clad$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:06
94	52	(((laser NEAR diode) with (ridge or stripe)) and (clad$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:10
101	10	(((laser NEAR diode) with (ridge or stripe)) and (clad$4 near (layer or region or medium or film)) and (active near (layer or region or medium or film)) and (contact near (layer or region or medium or film)) and electrode and 372/46) and third near clad$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 14:10
108	0	clad$ and laesr near diode and (etch$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:06
115.	320	clad$ and (laser near diode) and (etch$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:07
122	258	clad$ and (laser near diode) and (etch$4 near stop near layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:08
129	5	laser and clad$4 and active and contact and electrode and (injection near2 stripe) and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:08
136	166	laser and clad$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:40
143	98	(laser and clad$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:33
150	1	((laser and clad$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46) and saturatable near absorption	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:35

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157	8	((laser and clad$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film))) and 372/46) and saturable near absorption	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:35
164	1	(laser near diode) and clad$4 and active and contact and electrode and (ridge or stripe) and (etching near stop near (layer or region or medium or film)) and saturable near absorption and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:41
-	33	(laser near diode) and clad$4 and active and contact and electrode and (injection near3 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/02 14:55
-	26	((laser near diode) and clad$4 and active and contact and electrode and (injection near3 stripe) and voltage) and 372/$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/02 14:55
-	53	laser and clad$4 and active and contact and electrode and (injection near3 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:01
-	10	laser and clad$4 and active and contact and electrode and (injection near stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 06:12
-	29	laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:47
-	2	laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etching near stop near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:07
-	2	laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch$4 near stop)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 16:06
-	12	laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch$4 near (layer or region or medium or film))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:57
-	1	(laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch$4 near (layer or region or medium or film))) and third near clad	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 08:57
-	1	(laser and clad$4 and active and contact and electrode and (injection near2 stripe) and voltage and (etch$4 near (layer or region or medium or film))) and third near clad$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:09

-	364	((laser or diode) with (ridge or stripe)) and clad$4 and active and contact and electrode and voltage and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:06
-	137	((laser NEAR diode) with (ridge or stripe)) and clad$4 and active and contact and electrode and voltage	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:07
-	12	(((laser NEAR diode) with (ridge or stripe)) and clad$4 and active and contact and electrode and voltage) and third near clad$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 09:21
-	5	((((laser NEAR diode) with (ridge or stripe)) and clad$4 and active and contact and electrode and voltage) and third near clad$4) and 372/46	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/03 13:02